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DM74LS20 Dual 4-Input NAND Gate

FAIRCHILD

SEMICONDUCTOR

DM74LS20 Dual 4-Input NAND Gate

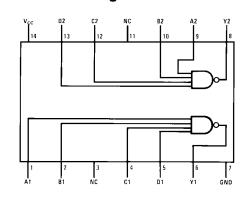
General Description

This device contains two independent gates each of which performs the logic NAND function.

Ordering Code:

Order Number	Package Number	Package Description			
DM74LS20M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow			
DM74LS20N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide			
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.					

Connection Diagram



Function Table

Y = ABCD

	Inputs				
Α	В	С	D	Y	
Х	Х	Х	L	Н	
Х	Х	L	Х	н	
Х	L	Х	Х	н	
L	Х	Х	Х	н	
н	н	н	н	L	

H = HIGH Logic Level

L = LOW Logic Level X = Either LOW or HIGH Logic Level

Absolute Maximum Ratings(Note 1)

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V _{CC}	Supply Voltage	4.75	5	5.25	V
V _{IH}	HIGH Level Input Voltage	2			V
V _{IL}	LOW Level Input Voltage			0.8	V
I _{OH}	HIGH Level Output Current			-0.4	mA
I _{OL}	LOW Level Output Current			8	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

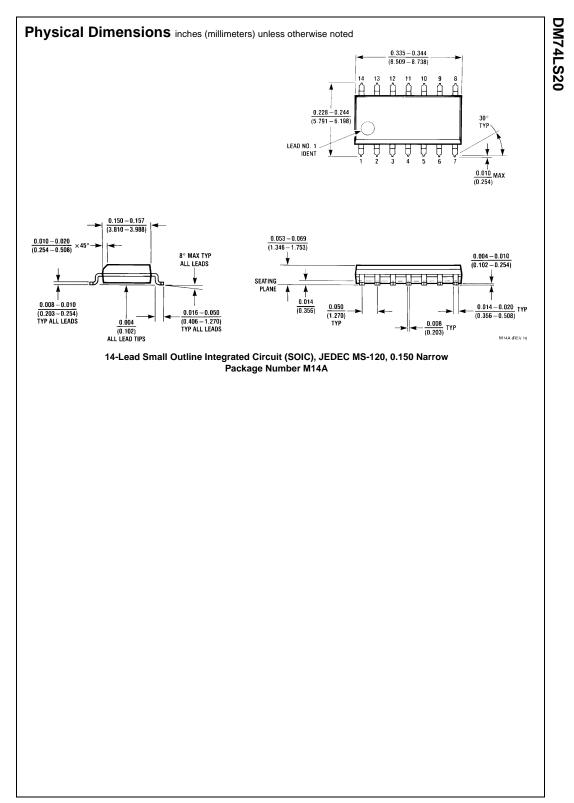
Symbol	Parameter	Conditions	Min	Typ (Note 2)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$			-1.5	V
V _{OH}	HIGH Level Output Voltage	$V_{CC} = Min, I_{OH} = Max,$ $V_{IL} = Max$	2.7	3.4		V
V _{OL}	LOW Level Output Voltage	$V_{CC} = Min, I_{OL} = Max,$ $V_{IH} = Min$		0.35	0.5	V
		$I_{OL} = 4 \text{ mA}, V_{CC} = Min$		0.25	0.4	
l _l	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 7V$			0.1	mA
I _{IH}	HIGH Level Input Current	$V_{CC} = Max, V_I = 2.7V$			20	μΑ
IIL	LOW Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-0.36	mA
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 3)	-20		-100	mA
ICCH	Supply Current with Outputs HIGH	V _{CC} = Max	İ	0.4	0.8	mA
ICCL	Supply Current with Outputs LOW	V _{CC} = Max		1.2	2.2	mA
Note 2: All	typicals are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.	-	•	•	•	•

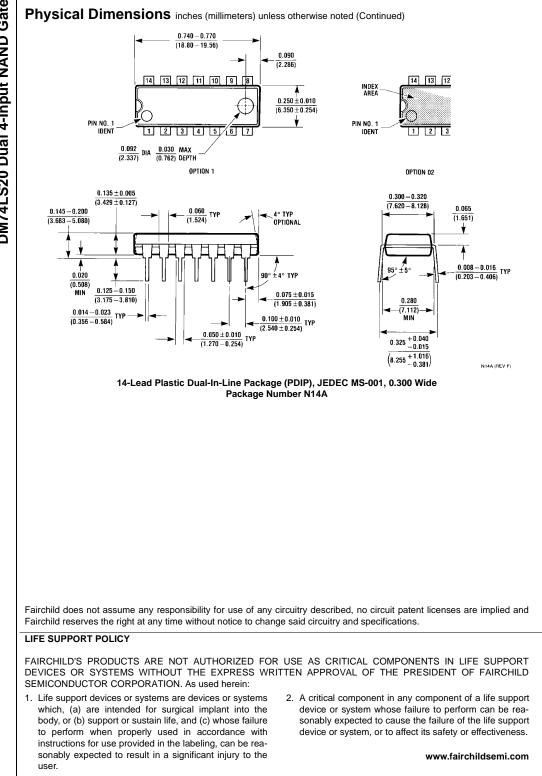
Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics

at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$

	Parameter	$R_L = 2 k\Omega$				
Symbol		C _L = 15 pF		C _L = 50 pF		Units
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Time LOW-to-HIGH Level Output	3	10	4	15	ns
t _{PHL}	Propagation Delay Time HIGH-to-LOW Level Output	3	10	4	15	ns





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